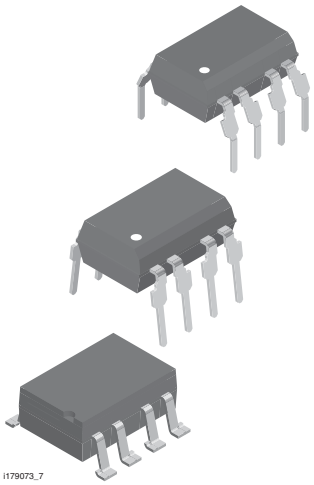
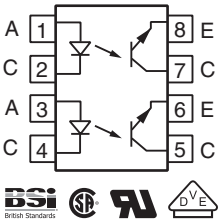
Optocoupler, Phototransistor Output, Dual Channel





FEATURES

- Dual version of SFH610 series
- Isolation test voltage, 5300 V_{RMS}
- V_{CEsat} 0.25 (≤ 0.4) V at I_F = 10 mA, I_C = 2.5 mA
- V_{CEO} = 70 V
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e3

RoHS COMPLIANT

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884)/DIN EN 60747-5-5 pending
- CSA 93751
- BSI IEC 60950; IEC 60065

DESCRIPTION

The ILD610 series is a dual channel optocoupler series for high density applications. Each channel consists of an optically coupled pair with a gallium arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD610 series is the dual version of SFH610 series and uses a repetitive pin-out configuration instead of the more common alternating pin-out used in most dual couplers.

ORDERING INFORMATION

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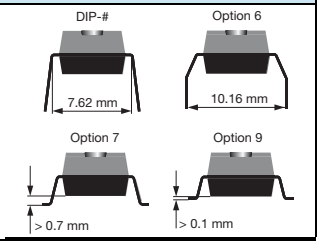
PART NUMBER							CTR BIN	PACKAGE OPTION				TAPE AND REEL



AGENCY CERTIFIED/PACKAGE	CTR (%)			
UL, CSA, BSI	**40 to 80**	**63 to 125**	**100 to 200**	**160 to 320**
DIP-8	ILD610-1	-	ILD610-3	-
DIP-8, 400 mil, option 6	-	-	ILD610-3X006	-
SMD-8, option 7	-	ILD610-2X007T	-	-
SMD-8, option 9	-	-	ILD610-3X009	ILD610-4X009

Note

- Additional options may be possible, please contact sales office.

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
INPUT				
Reverse voltage		V_R	6.0	V
Surge forward current	t ≤ 1.0 ms	I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.3	mW/°C
Forward continuous current		I_F	60	mA
OUTPUT				
Collector emitter voltage		V_{CE}	70	V
Collector current		I_C	50	mA
	t ≤ 1.0 ms	I_C	100	mA
Power dissipation		P_{diss}	150	mW
Derate linearly from 25 °C			2.0	mW/°C
COUPLER				
Isolation test voltage	t = 1.0 s	V_{ISO}	5300	V_{RMS}
Isolation resistance	V_{IO} = 500 V, T_{amb} = 25 °C	R_{IO}	≥ 10^{12}	Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R_{IO}	≥ 10^{11}	Ω
Storage temperature		T_{stg}	- 55 to + 150	°C
Operating temperature		T_{amb}	- 55 to + 100	°C
Junction temperature		T_j	100	°C
Lead soldering time at 260 °C			10	s

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT							
Forward voltage	I_F = 60 mA		V_F		1.25	1.65	V
Reverse current	V_R = 6.0 V		I_R		0.01	10	µA
Capacitance	V_R = 0 V, f = 1.0 MHz		C_O		25		pF
OUTPUT							
Collector emitter breakdown voltage	I_C = 10 mA, I_E = 10 µA		BV_{CEO}	70	90		V
			BV_{CEO}	6.0	7.0		V
Collector emitter dark current	V_{CE} = 10 V		I_{CEO}		2.0	50	nA
Collector emitter capacitance	V_{CE} = 5.0 V, f = 1.0 MHz		C_{CE}		7.0		pF
Collector emitter leakage current	V_{CE} = 10 V	ILD610-1	I_{CEO}		2.0	50	nA
		ILD610-2	I_{CEO}		2.0	50	nA
		ILD610-3	I_{CEO}		5.0	100	nA
		ILD610-4	I_{CEO}		5.0	100	nA
COUPLER							
Collector emitter saturation voltage	I_F = 10 mA, I_C = 2.5 mA		V_{CEsat}		0.25	0.40	V
Coupling capacitance			C_C		0.35		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
CTR (1)	I_F = 10 mA, V_{CE} = 5.0 V	ILD610-1	CTR	40		80	%
		ILD610-2	CTR	63		125	%
		ILD610-3	CTR	100		200	%
		ILD610-4	CTR	160		320	%
	I_F = 1.0 mA, V_{CE} = 5.0 V	ILD610-1	CTR	13			%
		ILD610-2	CTR	22			%
		ILD610-3	CTR	34			%
		ILD610-4	CTR	56			%

Note

(1) CTR will match within a ratio of 1.7:1

SWITCHING CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
NON-SATURATED							
Rise time	V_{CC} = 5.0 V, R_L = 75 Ω, I_F = 10 mA	ILD610-1	t_r		2.0		µs
		ILD610-2			2.5		
		ILD610-3			2.9		
		ILD610-4			3.3		
Fall time	V_{CC} = 5.0 V, R_L = 75 Ω, I_F = 10 mA	ILD610-1	t_f		2.0		µs
		ILD610-2			2.6		
		ILD610-3			3.1		
		ILD610-4			3.5		
Turn-on time	V_{CC} = 5.0 V, R_L = 75 Ω, I_F = 10 mA	ILD610-1	t_{on}		3.0		µs
		ILD610-2			3.2		
		ILD610-3			3.6		
		ILD610-4			4.1		
Turn-off time	V_{CC} = 5.0 V, R_L = 75 Ω, I_F = 10 mA	ILD610-1	t_{off}		2.9		µs
		ILD610-2			3.4		
		ILD610-3			3.7		
		ILD610-4			4.1		
SATURATED							
Rise time	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 20 mA	ILD610-1	t_r		2.0		µs
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-2			2.8		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-3			2.8		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 5 mA	ILD610-4			4.6		
Fall time	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 20 mA	ILD610-1	t_f		11		µs
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-2			14		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-3			14		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 5 mA	ILD610-4			15		
Turn-on time	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 20 mA	ILD610-1	t_{on}		3.0		µs
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-2			4.3		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-3			4.3		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 5 mA	ILD610-4			6.0		
Turn-off time	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 20 mA	ILD610-1	t_{off}		18		µs
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-2			25		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 10 mA	ILD610-3			25		
	V_{CC} = 5.0 V, R_L = 1.0 kΩ, I_F = 5 mA	ILD610-4			25		

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

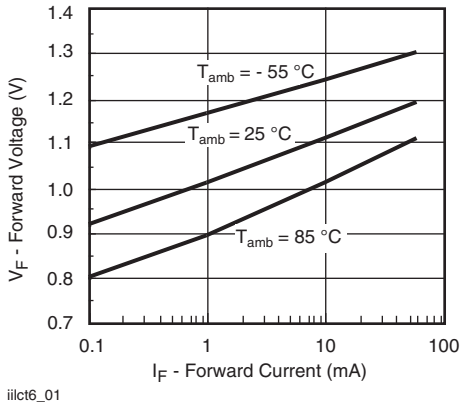


Fig. 1 - Forward Voltage vs. Forward Current

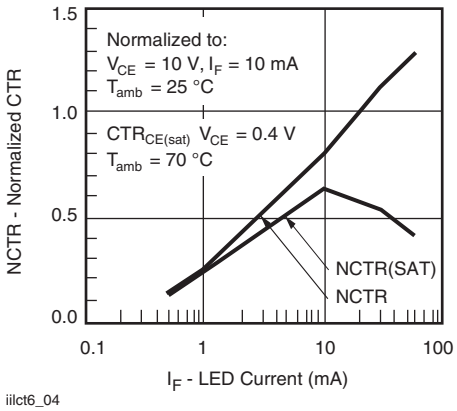


Fig. 4 - Normalized Non-Saturated and Saturated CTR vs. LED Current

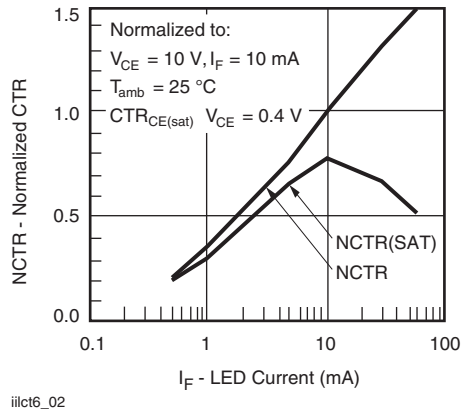


Fig. 2 - Normalized Non-Saturated and Saturated CTR vs. LED Current

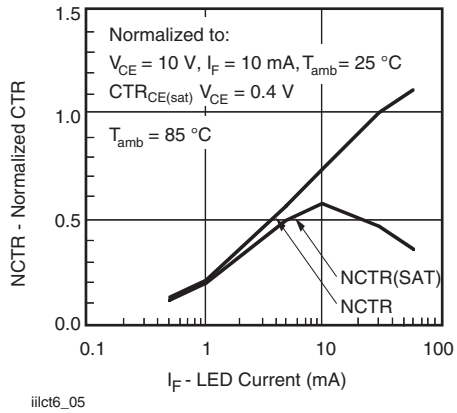


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

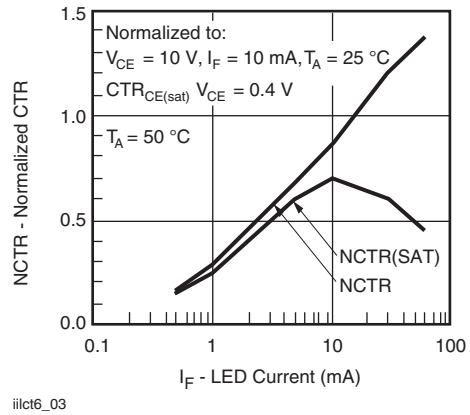


Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current

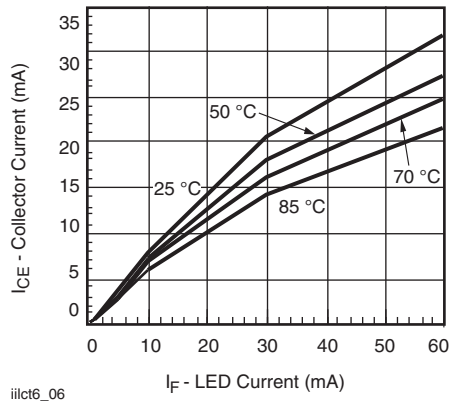


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current

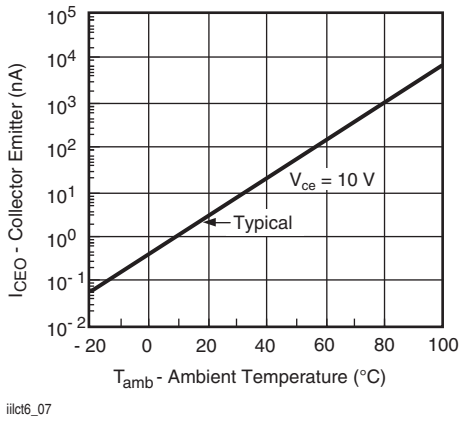


Fig. 7 - Collector Emitter Leakage Current vs.Temperature

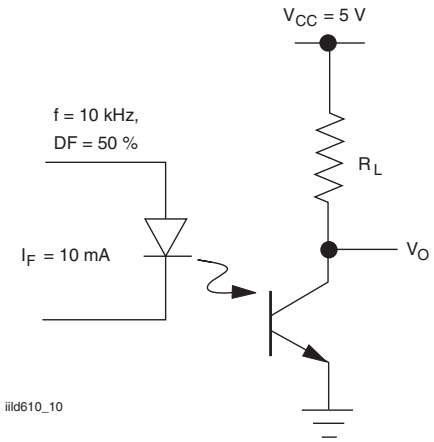


Fig. 10 - Non-Saturated Switching Schematic

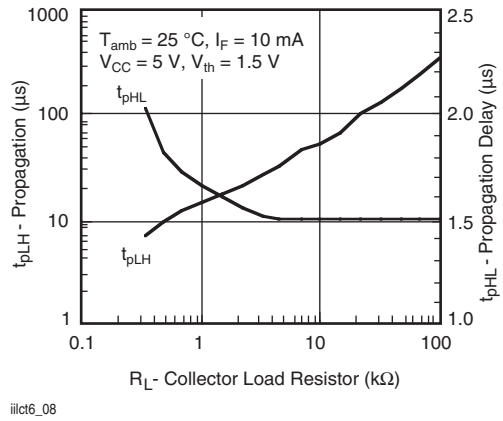


Fig. 8 - Propagation Delay vs. Collector Load Resistor

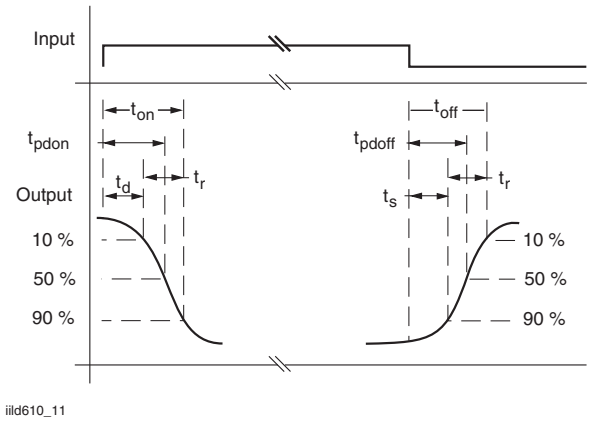


Fig. 11 - Saturated Switching Time Test Waveform

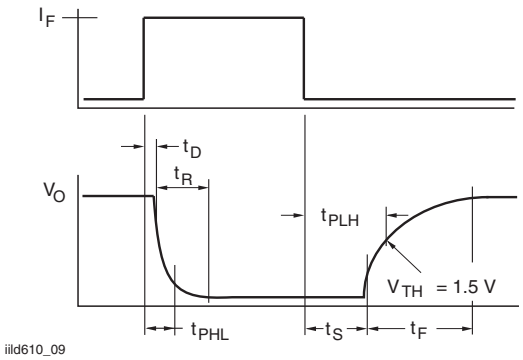
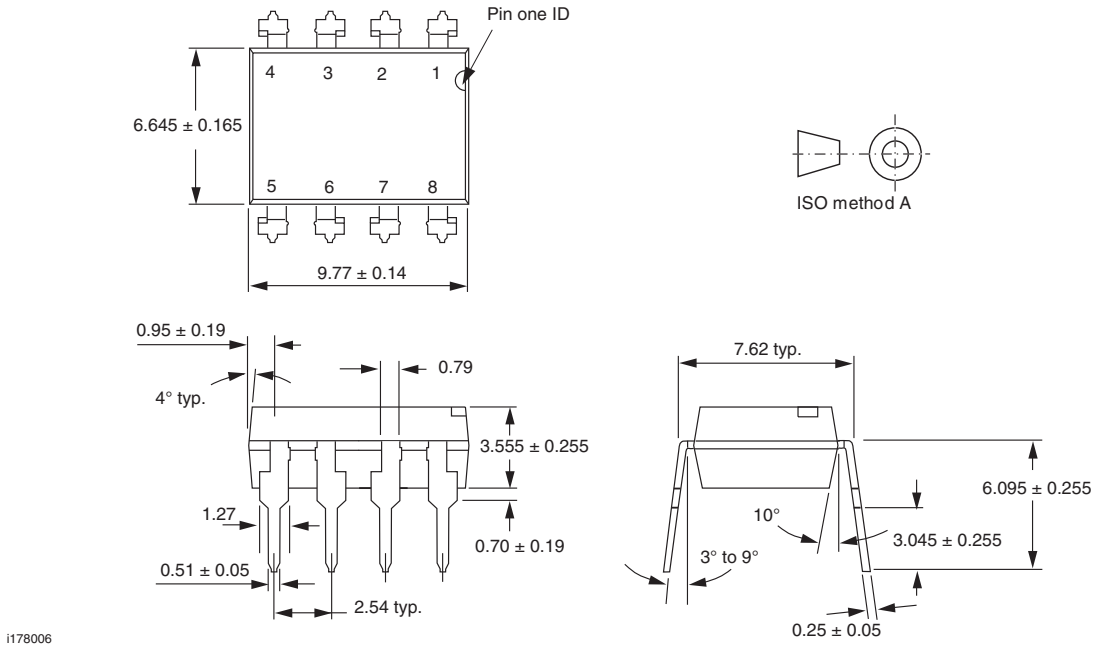
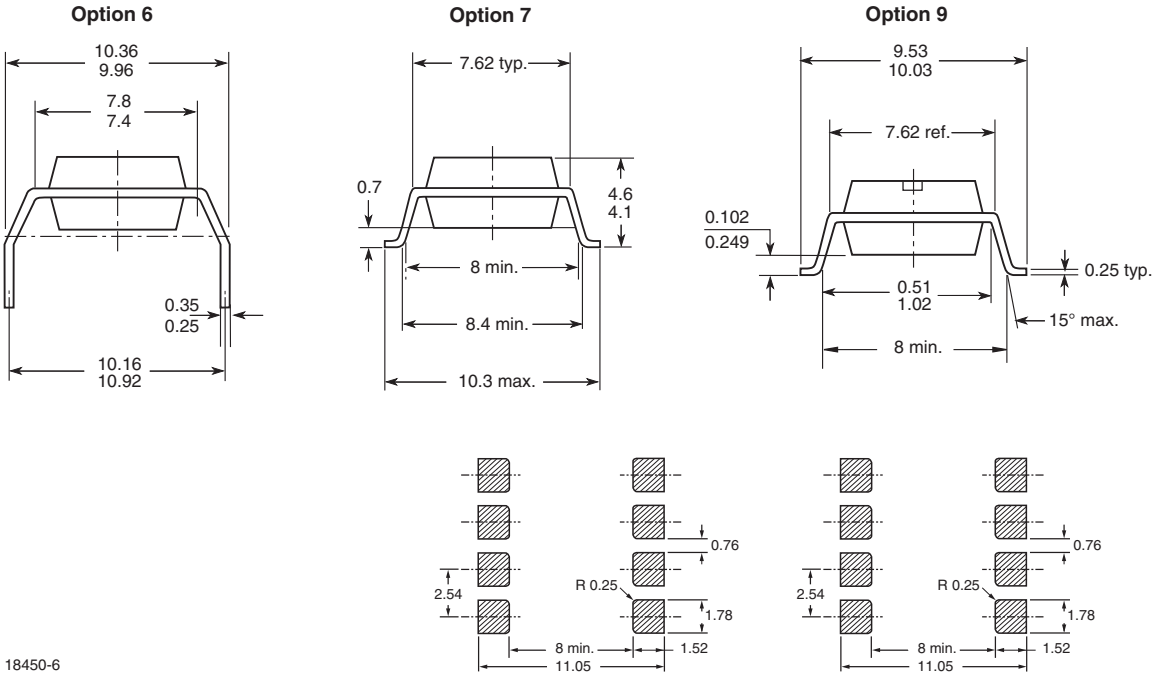


Fig. 9 - Switching Timing

PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING

Notes

- Only option 1 and 7 reflected in the package marking
- Tape and reel suffix (T) is not part of the package marking

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